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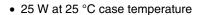
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Vishay Sfernice



Surface Mounted Power Resistor Thick Film Technology

FEATURES

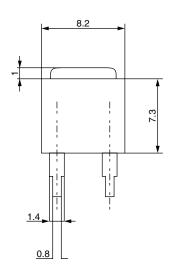


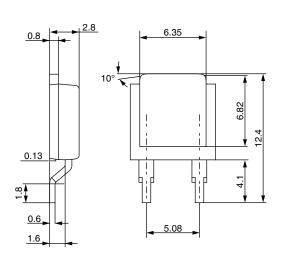


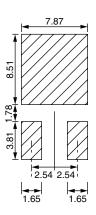
• Surface mounted resistor - TO-252 (D-PAK) style RoHS package

- Wide resistance range: 0.016 Ω to 700 $k\Omega$
- Non inductive
- RoHS compliant
- · Resistor isolated from metal tab
- Solder reflow secure at 270 °C/10 s, MSL = 1

DIMENSIONS in millimeters







MECHANICAL SPECIFICATIONS

Mechanical Protection Molded **Resistive Element** Thick film Substrate Alumina Connections Tinned copper Weight 2 g max.

DIMENSIONS

Standard Package TO-252 style (D-PAK)

ENVIRONMENTAL SPECIFICATIONS

- 55 °C to + 150 °C **Temperature Range Climatic Category** 55/150/56

ELECTRICAL SPECIFICATIONS			
Resistance Range	0.016 Ω to 700 k Ω		
Tolerances	\pm 1 % to \pm 10 % from 0.016 Ω to 0.049 Ω only \pm 5 % and \pm 10 % available		
Power Rating and Thermal Resistance	25 W at + 25 °C case temperature R _{TH (j - c)} : 5 °C/W		
Temperature Coefficient	See Special Features table		
Standard	± 150 ppm/°C		
Limiting Element Voltage U _L	200 V		
Dielectric Strength IEC 60115-1	1500 V _{RMS} - 1 min - 15 mA max. (between terminals and board)		
Insulation Resistance	$\geq 10^4 \text{M}\Omega$		
Inductance	≤ 0.1 μH		
Critical Resistance	1.6 kΩ		

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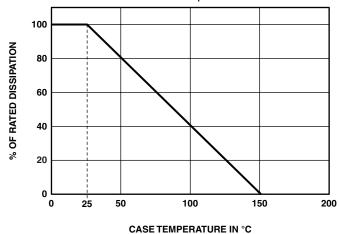
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SPECIAL FEATURES				
Resistance Values	≥ 0.016	≥ 0.1	≥ 0.5	
Typical Temperature Coefficient (- 55 °C to + 150 °C)	± 800 ppm/°C	± 250 ppm/°C	± 150 ppm/°C	

PERFORMANCE				
TESTS	CONDITIONS	REQUIREMENTS		
Momentary Overload	IEC 60115-1 § 4.13 1.5 Pr/5 s Us ≤ 1.5 U _L	± (0.25 % + 0.005 Ω)		
Rapid Temperature Change	IEC 60115-1 Tests Na 5 cycles - 1 h - 55 °C to + 150 °C	± (0.5 % + 0.005 Ω)		
Load Life	IEC 60115-1 1000 h Pr at + 25 °C case temperature	± (1 % + 0.005 Ω)		
Humidity (Steady State)	IEC 60115-1 IEC 60068-2-3 Test Ca: 56 days RH 95 % 85 °C	± (0.5 % + 0.005 Ω)		
Vibration	IEC 60115-1 IEC 60068-2-6 Test Fc: 10 to 2000 Hz	± (0.2 % + 0.005 Ω)		
Shear (Adhesion) Test	IEC 60115-1 IEC 60068-2-21 Test Ue3/Shear: 5 N/10 s	No visible damage		
Substrate Bending Test	IEC 60115-1 IEC 60068-2-21 Test Ue1: 2 mm/3 times	± (0.25 % + 0.005 Ω)		

POWER RATING CHART

The temperature of the case should be maintained within the limits specified.



ASSEMBLY SPECIFICATIONS					
For the assembly on board, we recommend the lead (Pb)-free thermal profile as per J-STD-020C					
TESTS	CONDITIONS	REQUIREMENTS			
Resistance to Soldering Heat	IEC 60115-1 IEC 60068-2-58 Solder Bath method: 270 °C/10 s	± (0.5 % + 0.005 Ω)			
Moisture Sensitivity Level (MSL)	IPC/JEDEC J-STD-020C 85 °C/85 % RH/168 h	Level: 1 + Pass requirements of TCR Overload and Dielectic Strength after MSL			

DTO25

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Surface Mounted Power Resistor Thick Film Technology



CHOISE OF THE BOARD

The user must choose the board according to the working conditions of the component (power, room temperature). Maximum working temperature must not exceed 150 °C. The dissipated power is simply calculated by the following ratio:

$$P = \frac{\Delta T}{[R_{TH (j-c)}] + [R_{TH (c-a)}]}$$

P: Expressed in W

ΔΤ: Difference between maximum working temperature and room temperature

Thermal resistance value measured between resistive layer and outer side of the resistor. It is the thermal R_{TH (i - c)}:

resistance of the component: 5 °C/W.

Thermal resistance value measured between outer side of the resistor and room temperature. It is the thermal $R_{TH(c-a)}$:

resistance of the solder layer (according the quality of the soldering) and the thermal resistance of the board.

R_{TH (c - a)} for DTO25 power rating 3 W at ambient temperature + 25 °C.

Thermal resistance $R_{TH\ (i-c)}$: 5 °C/W

Considering equation (1) we have:

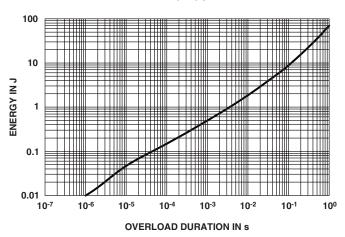
 $\Delta T = 150 \, ^{\circ}\text{C} - 25 \, ^{\circ}\text{C} = 125 \, ^{\circ}\text{C}$

 $\begin{array}{l} R_{TH~(j~-c)} + R_{TH~(c~-a)} = \Delta T/P = 125/3 = 41.7~^{\circ}C/W \\ R_{TH~(c~-a)} = 41.7~^{\circ}C/W - 5~^{\circ}C/W = 36.7~^{\circ}C/W \end{array}$

ACCIDENTAL OVERLOAD

In any case the applied voltage must be lower than the maximum overload voltage of Us = 375 V. The values indicated on the graph below are applicable to resistors onto a board.

ENERGY CURVE



Single Pulse:

These informations are for a single pulse on a cold resistor at 25 °C (not already used for a dissipation) and for pulses of 100 ms maximum duration.

The formula used to calculate E is:

$$E = P \times t = \frac{U^2}{R} \times t$$

with:

E(J): Pulse energy P(W): Pulse power t (s): Pulse duration U(V): Pulse voltage $R(\Omega)$: Resistor

The energy calculated must be less than that allowed by the graph.

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Repetitive or Superimposed Pulses:

The following formula is used to calculate the "equivalent" energy of a repetitive pulse or the "equivalent energy" of a pulse on a resistor that is already dissipating power.

$$E_{c} = E \times \left(1 + \frac{P_{a}}{P_{r}}\right)$$

with:

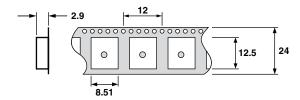
E_c (J): Equivalent pulse energyE (J): Known pulse energyP_r: Resistor power rating

*P*_a: Mean power being dissipated

The energy calculated must be less than that allowed by the graph and the average power dissipated (P_a) must not exceed the continuous power of resistor.

PACKAGING

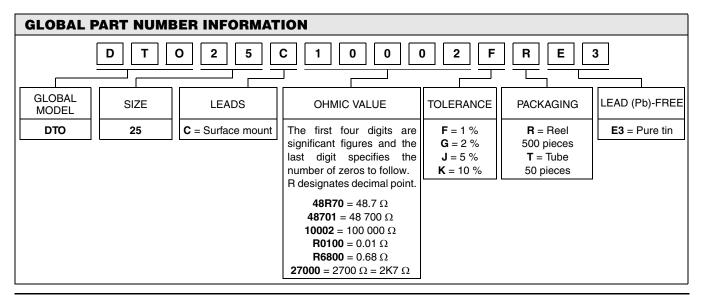
- Reel
- Tube
- Tape dimensions (mm) for reel:



MARKING

Model, Style, Resistance Value (in Ω), Tolerance (in %), Manufacturing Date, Vishay Trademark

ORDERING INFORMATION						
DTO	25	С	100 k Ω	± 1 %	XXX	e3
MODEL	STYLE	CONNECTIONS	RESISTANCE VALUE	TOLERANCE	CUSTOM DESIGN	LEAD (Pb)-FREE
				$F = \pm 1 \%$ $G = \pm 2 \%$ $J = \pm 5 \%$ $K = \pm 10 \%$	Optional on request: shape, etc	





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